

FS70KM-06

High-Speed Switching Use Nch Power MOS FET

REJ03G1427-0200

(Previous: MEJ02G0096-0101) Rev.2.00

Aug 07, 2006

Features

• Drive voltage: 10 V

 $\bullet \quad V_{DSS}: 60 \text{ V}$

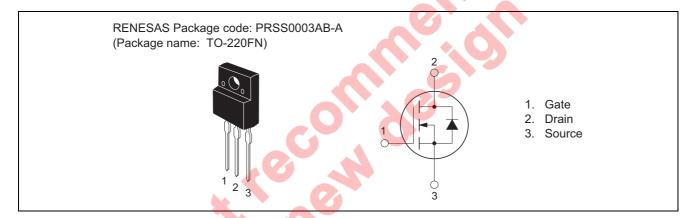
• $r_{DS(ON) (max)}$: 7.5 m Ω

• I_D: 70 A

• Integrated Fast Recovery Diode (TYP.): 85 ns

• Viso: 2000 V

Outline



Applications

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

Maximum Ratings

 $(Tc = 25^{\circ}C)$

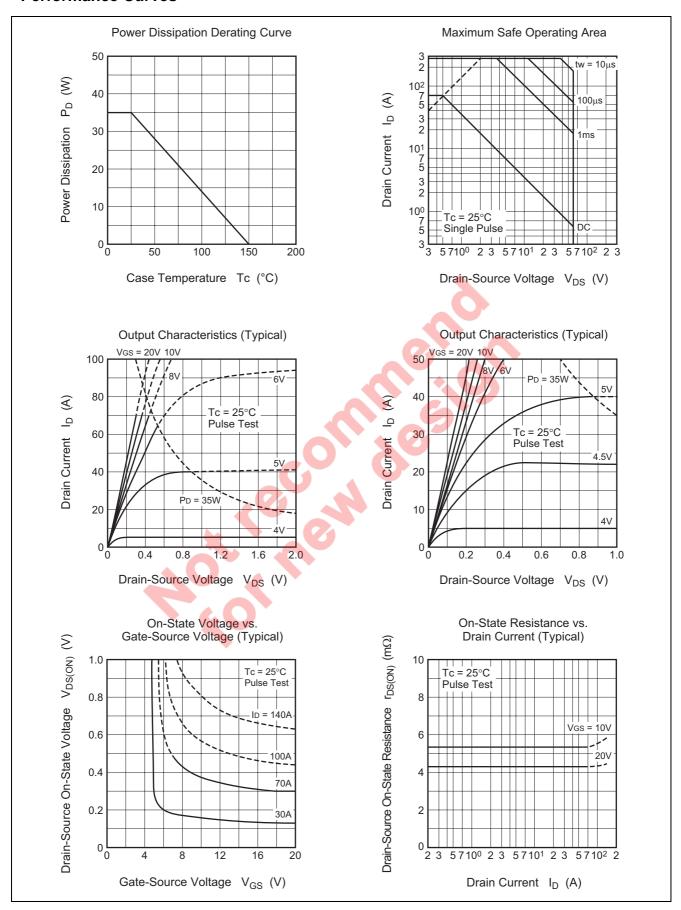
Parameter	Symbol	Ratings	Unit	Conditions
Drain-source voltage	V _{DSS}	60	V	V _{GS} = 0 V
Gate-source voltage	V_{GSS}	±20	V	$V_{DS} = 0 V$
Drain current	I _D	70	А	
Drain current (Pulsed)	I _{DM}	280	А	
Avalanche drain current (Pulsed)	I _{DA}	70	А	L = 100 μH
Source current	I _S	70	А	
Source current (Pulsed)	I _{SM}	280	А	
Maximum power dissipation	P _D	35	W	
Channel temperature	Tch	- 55 to +150	°C	
Storage temperature	Tstg	- 55 to +150	°C	
Isolation voltage	Viso	2000	V	AC for 1 minute,
				Terminal to case
Mass	_	2.0	g	Typical value

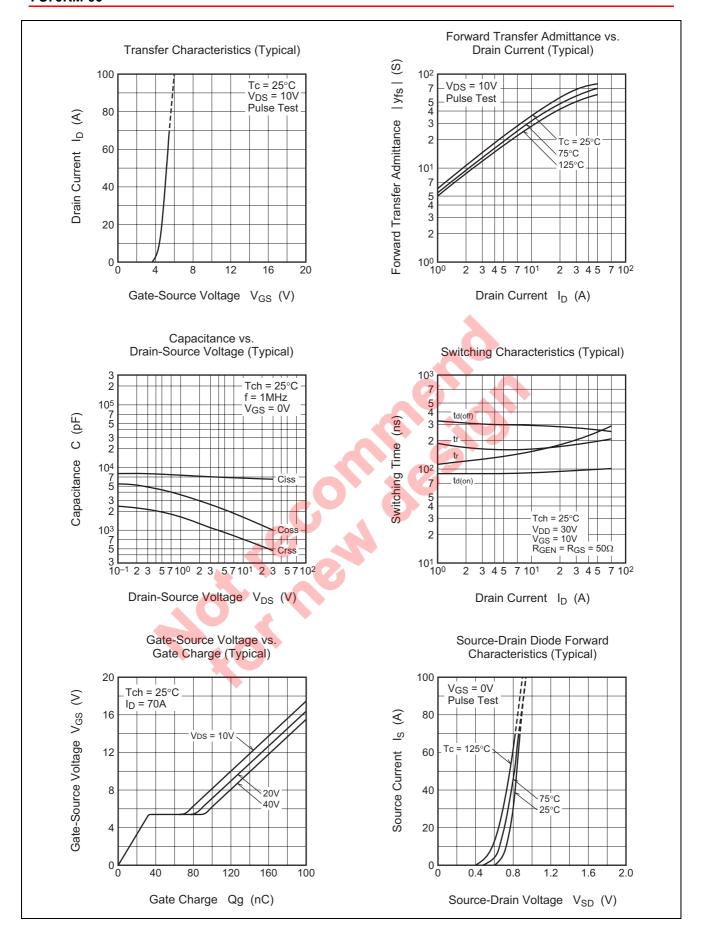
Electrical Characteristics

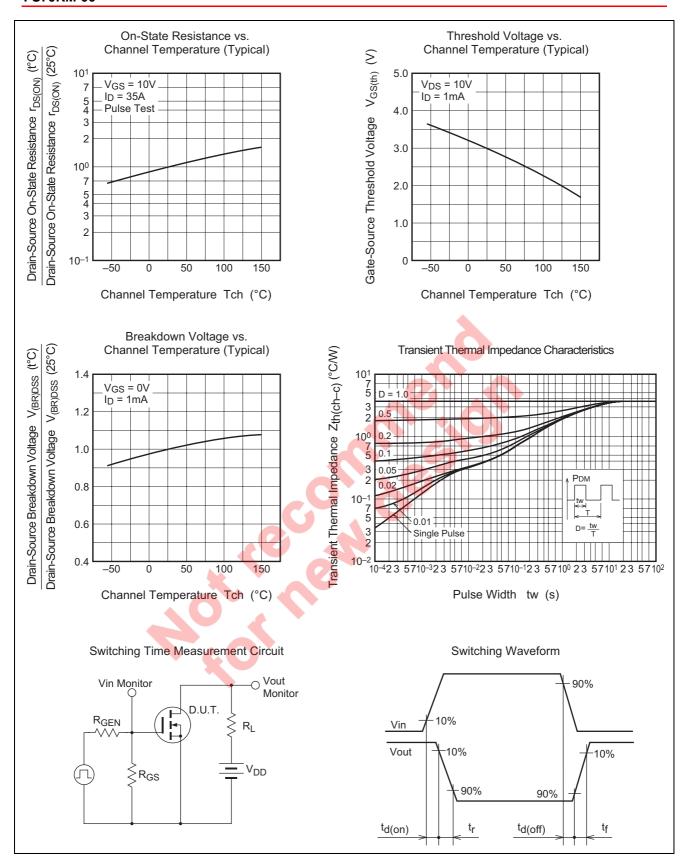
 $(Tch = 25^{\circ}C)$

Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions	
Drain-source breakdown voltage	V _{(BR)DSS}	60		_	V	I _D = 1 mA, V _{GS} = 0 V	
Gate-source leakage current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	
Drain-source leakage current	I _{DSS}	_	_	0.1	mA	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	
Gate-source threshold voltage	V _{GS(th)}	2.0	3.0	4.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$	
Drain-source on-state resistance	r _{DS(ON)}	_	5.7	7.5	mΩ	$I_D = 35 \text{ A}, V_{GS} = 10 \text{ V}$	
Drain-source on-state voltage	V _{DS(ON)}	_	0.200	0.263	V	I _D = 35 A, V _{GS} = 10 V	
Forward transfer admittance	yfs	50	70		S	I _D = 35 A, V _{DS} = 10 V	
Input capacitance	Ciss	_	6540	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$	
Output capacitance	Coss	_	1640	_	pF	f = 1MHz	
Reverse transfer capacitance	Crss	_	790	_	pF		
Turn-on delay time	t _{d(on)}		95		ns	$V_{DD} = 30 \text{ V}, I_D = 35 \text{ A},$	
Rise time	t _r		195		ns	V _{GS} = 10 V,	
Turn-off delay time	t _{d(off)}		290		ns	$R_{GEN} = R_{GS} = 50 \Omega$	
Fall time	t _f	_	210	_	ns		
Source-drain voltage	V _{SD}	_	1.0	1.5	V	I _S = 35 A, V _{GS} = 0 V	
Thermal resistance	R _{th(ch-c)}	_	_	3.57	°C/W	Channel to case	
Reverse recovery time	t _{rr}	_	85		ns	$I_S = 70 \text{ A}, d_{is}/d_t = -100 \text{ A/}\mu\text{s}$	
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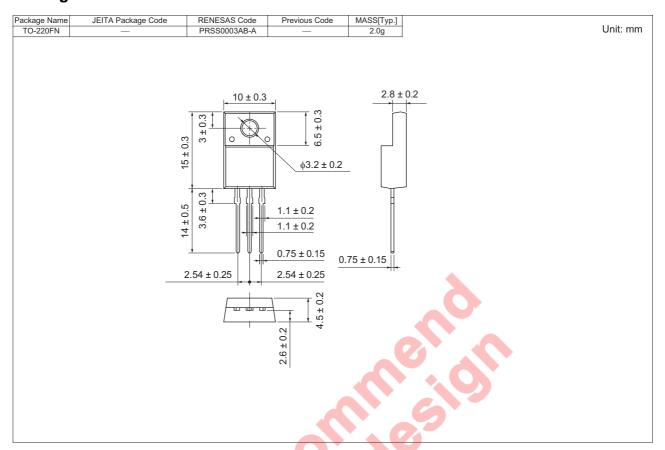
Performance Curves







Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)	50	Type name	FS70KM-06
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	FS70KM-06-A8

Note: Please confirm the specification about the shipping in detail.

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